TOSHIBA CMOS Digital Integrated Circuit Silicon Monolithic

TC74HC390AP,TC74HC390AF,TC74HC390AFN

Dual Decade Counter

Note: xxxFN (JEDEC SOP) is not available in Japan.

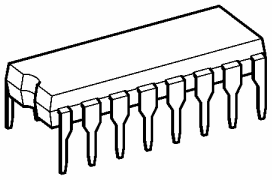
The TC74HC390A is a high speed CMOS DUAL DECADE COUNTER fabricated with silicon gate C²MOS technology.

It achieves the high speed operation similar to equivalent LSTTL while maintaining the CMOS low power dissipation.

It consists of two independent 4-bit counters, each composed of a divide-by-two and a divide-by-five counter. The divide-by-two counter is incremented on the negative going transition of clock A ($\overline{CKA}$). The divided-by-five counter is incremented on the negative going transition of clock B ($\overline{CKB}$). The counter can be cascaded to form decade, bi-quinary, or various combinations up to a divide-by-100 counter. When the CLR input is set high, the Q outputs are set to low independent of the clock inputs.

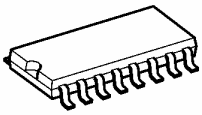
All inputs are equipped with protection circuits against static discharge or transient excess voltage.

TC74HC390AP



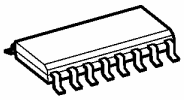
DIP16-P-300-2.54A

TC74HC390AF



SOP16-P-300-1.27A

TC74HC390AFN



SOL16-P-150-1.27

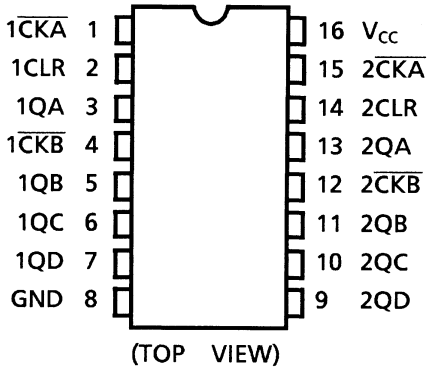
Weight

DIP16-P-300-2.54A	: 1.00 g (typ.)
SOP16-P-300-1.27A	: 0.18 g (typ.)
SOL16-P-150-1.27	: 0.13 g (typ.)

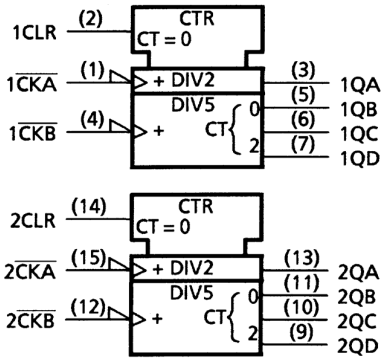
Features

- High speed: f_{max} = 84 MHz (typ.) at V_{CC} = 5 V
- Low power dissipation: I_{CC} = 4 μA (max) at Ta = 25°C
- High noise immunity: $V_{NIH} = V_{NIL}$ = 28% V_{CC} (min)
- Output drive capability: 10 LSTTL loads
- Symmetrical output impedance: $|I_{OH}| = I_{OL}$ = 4 mA (min)
- Balanced propagation delays: $t_{pLH} \simeq t_{pHL}$
- Wide operating voltage range: V_{CC} (opr) = 2~6 V
- Pin and function compatible with 74LS390

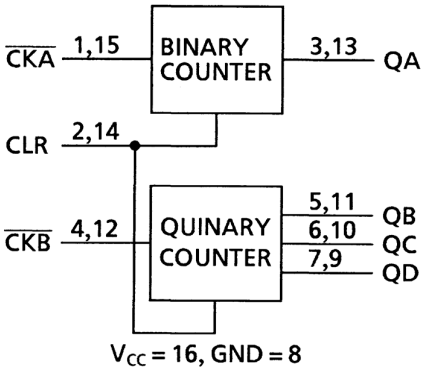
Pin Assignment



IEC Logic Symbol



Block Diagram

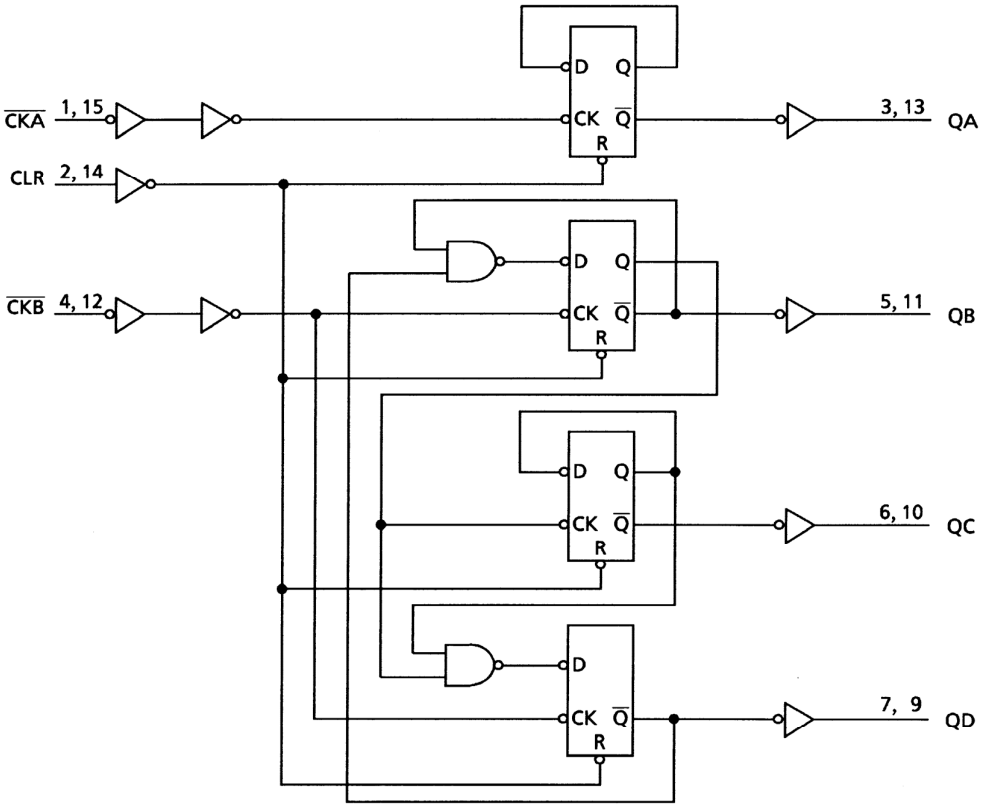


Truth Table

Inputs			Outputs			
$\overline{CKA}$	$\overline{CKB}$	CLR	QA	QB	QC	QD
X	X	H	L	L	L	L
↓	X	L	Binary Count Up			
X	↓	L	Quinary Count Up			

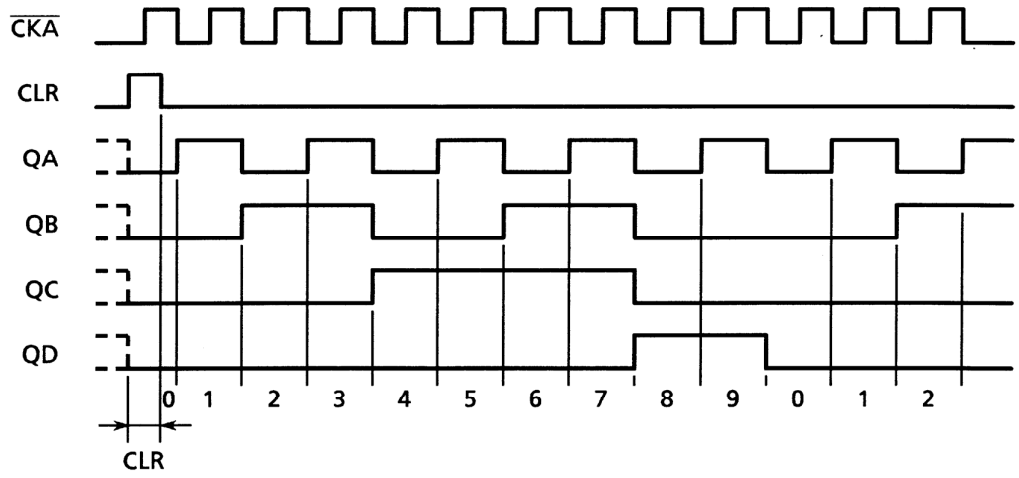
X: Don't care

System Diagram (1/2 package)



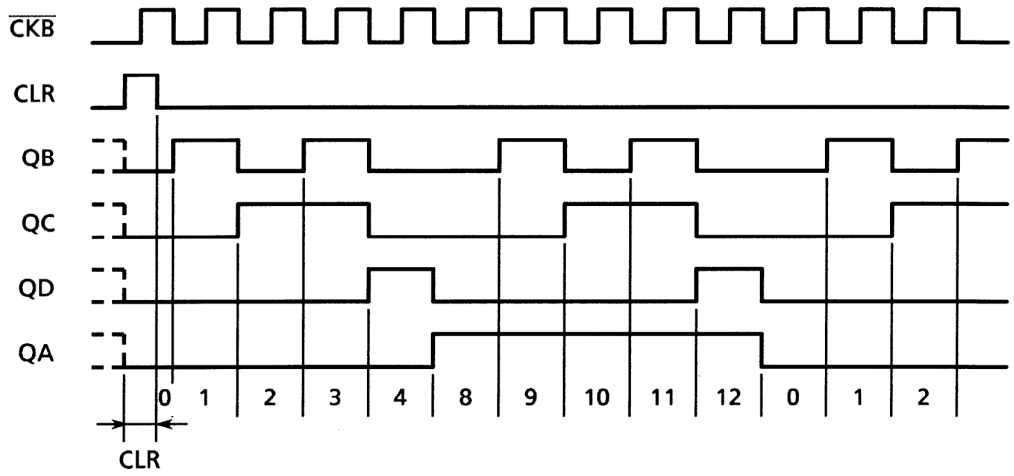
Timing Chart

(1) BCD count sequence (Note)



Note: QA connected to $\overline{CKB}$

(2) BI-quinary count sequence (Note)



Note: QD connected to $\overline{CKA}$

Absolute Maximum Ratings (Note 1)

Characteristics	Symbol	Rating	Unit
Supply voltage range	V_{CC}	−0.5~7	V
DC input voltage	V_{IN}	−0.5~V_{CC} + 0.5	V
DC output voltage	V_{OUT}	−0.5~V_{CC} + 0.5	V
Input diode current	I_{IK}	±20	mA
Output diode current	I_{OK}	±20	mA
DC output current	I_{OUT}	±25	mA
DC V_{CC}/ground current	I_{CC}	±50	mA
Power dissipation	P_D	500 (DIP) (Note 2)/180 (SOP)	mW
Storage temperature	T_{stg}	−65~150	°C

Note 1: Exceeding any of the absolute maximum ratings, even briefly, lead to deterioration in IC performance or even destruction.
Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings and the operating ranges.
Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook (“Handling Precautions”/“Derating Concept and Methods”) and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Note 2: 500 mW in the range of Ta = −40 to 65°C. From Ta = 65 to 85°C a derating factor of −10 mW/°C shall be applied until 300 mW.

Operating Ranges (Note)

Characteristics	Symbol	Rating	Unit
Supply voltage	V_{CC}	2~6	V
Input voltage	V_{IN}	0~V_{CC}	V
Output voltage	V_{OUT}	0~V_{CC}	V
Operating temperature	T_{opr}	−40~85	°C
Input rise and fall time	t_r, t_f	0~1000 (V_{CC} = 2.0 V) 0~500 (V_{CC} = 4.5 V) 0~400 (V_{CC} = 6.0 V)	ns

Note: The operating ranges must be maintained to ensure the normal operation of the device.
Unused inputs must be tied to either VCC or GND.

Electrical Characteristics

DC Characteristics

Characteristics	Symbol	Test Condition		V_{CC} (V)	Ta = 25°C Min	Ta = 25°C Typ.	Ta = 25°C Max	Ta = −40~85°C Min	Ta = −40~85°C Max	Unit
High-level input voltage	V_{IH}	—		2.0	1.50	—	—	1.50	—	V
				4.5	3.15	—	—	3.15	—	
				6.0	4.20	—	—	4.20	—	
Low-level input voltage	V_{IL}	—		2.0	—	—	0.50	—	0.50	V
				4.5	—	—	1.35	—	1.35	
				6.0	—	—	1.80	—	1.80	
High-level output voltage	V_{OH}	V_{IN} = V_{IH} or V_{IL}	I_{OH} = −20 μA	2.0	1.9	2.0	—	1.9	—	V
				4.5	4.4	4.5	—	4.4	—	
				6.0	5.9	6.0	—	5.9	—	
			I_{OH} = −4 mA	4.5	4.18	4.31	—	4.13	—	
			I_{OH} = −5.2 mA	6.0	5.68	5.80	—	5.63	—	
Low-level output voltage	V_{OL}	V_{IN} = V_{IH} or V_{IL}	I_{OL} = 20 μA	2.0	—	0.0	0.1	—	0.1	V
				4.5	—	0.0	0.1	—	0.1	
				6.0	—	0.0	0.1	—	0.1	
			I_{OL} = 4 mA	4.5	—	0.17	0.26	—	0.33	
			I_{OL} = 5.2 mA	6.0	—	0.18	0.26	—	0.33	
Input leakage current	I_{IN}	V_{IN} = V_{CC} or GND		6.0	—	—	±0.1	—	±1.0	μA
Quiescent supply current	I_{CC}	V_{IN} = V_{CC} or GND		6.0	—	—	4.0	—	40.0	μA

Timing Requirements (input: $t_r = t_f = 6$ ns)

Characteristics	Symbol	Test Condition	V_{CC} (V)	Ta = 25°C Typ.	Ta = 25°C Limit	Ta = −40~85°C Limit	Unit
Minimum pulse width ($\overline{CK}$)	$t_{W(H)}$ $t_{W(L)}$	—	2.0	—	75	95	ns
			4.5	—	15	19	
			6.0	—	13	16	
Minimum pulse width (CLR)	$t_{W(H)}$	—	2.0	—	75	95	ns
			4.5	—	15	19	
			6.0	—	13	16	
Minimum removal time	t_{rem}	—	2.0	—	25	30	ns
			4.5	—	5	6	
			6.0	—	5	5	
Clock frequency ($\overline{CKA}$)	f	—	2.0	—	6	5	MHz
			4.5	—	32	26	
			6.0	—	38	31	
Clock frequency ($\overline{CKB}$)	f	—	2.0	—	6	5	MHz
			4.5	—	31	25	
			6.0	—	36	29	

AC Characteristics (C_L = 15 pF, V_{CC} = 5 V, Ta = 25°C input: $t_r = t_f$ = 6 ns)

Characteristics	Symbol	Test Condition	Min	Typ.	Max	Unit
Output transition time	t_{TLH} t_{THL}	—	—	4	8	ns
Propagation delay time ($\overline{CKA}$ -QA)	t_{pLH} t_{pHL}	—	—	10	20	ns
Propagation delay time ($\overline{CKA}$ -QC)	t_{pLH} t_{pHL}	QA connected to $\overline{CKB}$	—	29	51	ns
Propagation delay time ($\overline{CKB}$ -QB, QD)	t_{pLH} t_{pHL}	—	—	12	22	ns
Propagation delay time ($\overline{CKB}$ -QC)	t_{pLH} t_{pHL}	—	—	17	32	ns
Propagation delay time (CLR-Qn)	t_{pHL}	—	—	12	26	ns
Maximum clock frequency ($\overline{CKA}$)	f_{max}	—	35	84	—	MHz
Maximum clock frequency ($\overline{CKB}$)	f_{max}	—	33	65	—	MHz

AC Characteristics (C_L = 50 pF, input: $t_r = t_f$ = 6 ns)

Characteristics	Symbol	Test Condition		Ta = 25°C			Ta = −40~85°C		Unit
			V_{CC} (V)	Min	Typ.	Max	Min	Max	
Output transition time	t_{TLH} t_{THL}	—	2.0	—	30	75	—	95	ns
			4.5	—	8	15	—	19	
			6.0	—	7	13	—	16	
Propagation delay time ($\overline{CKA}$ -QA)	t_{pLH} t_{pHL}	—	2.0	—	39	120	—	150	ns
			4.5	—	13	24	—	30	
			6.0	—	11	20	—	26	
Propagation delay time ($\overline{CKA}$ -QC)	t_{pLH} t_{pHL}	QA connected to $\overline{CKB}$	2.0	—	102	290	—	365	ns
			4.5	—	34	58	—	73	
			6.0	—	29	49	—	62	
Propagation delay time ($\overline{CKB}$ -QB, QD)	t_{pLH} t_{pHL}	—	2.0	—	45	130	—	165	ns
			4.5	—	15	26	—	33	
			6.0	—	13	22	—	28	
Propagation delay time ($\overline{CKB}$ -QC)	t_{pLH} t_{pHL}	—	2.0	—	63	185	—	230	ns
			4.5	—	21	37	—	46	
			6.0	—	18	31	—	39	
Propagation delay time (CLR-Qn)	t_{pHL}	—	2.0	—	45	150	—	190	ns
			4.5	—	15	30	—	38	
			6.0	—	13	26	—	32	
Maximum clock frequency ($\overline{CKA}$)	f_{max}	—	2.0	6	20	—	5	—	MHz
			4.5	32	77	—	26	—	
			6.0	38	90	—	31	—	
Maximum clock frequency ($\overline{CKB}$)	f_{max}	—	2.0	6	15	—	5	—	MHz
			4.5	32	60	—	25	—	
			6.0	36	70	—	29	—	
Input capacitance	C_{IN}	—		—	5	10	—	10	pF
Power dissipation capacitance	C_{PD} (Note)	—		—	44	—	—	—	pF

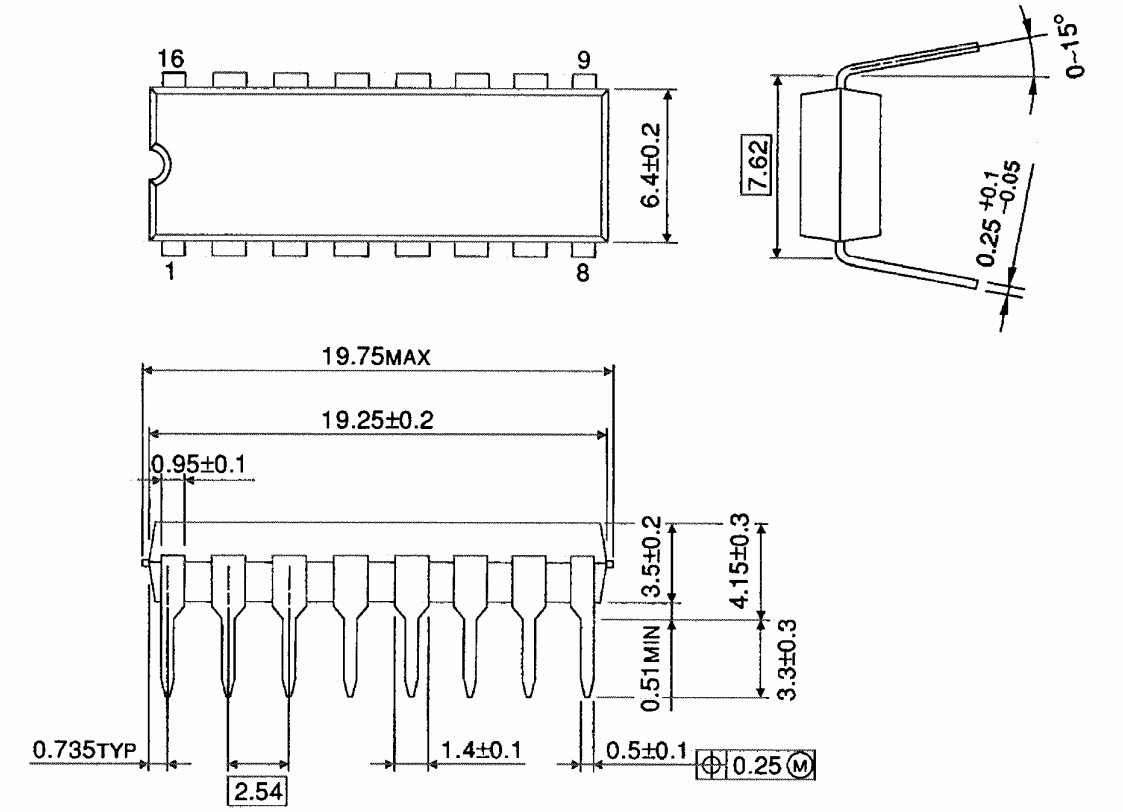
Note: C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load.

Average operating current can be obtained by the equation:

$$I_{CC}\ (opr) = C_{PD} \cdot V_{CC} \cdot f_{IN} + I_{CC}/2\ (per\ counter)$$

Package Dimensions

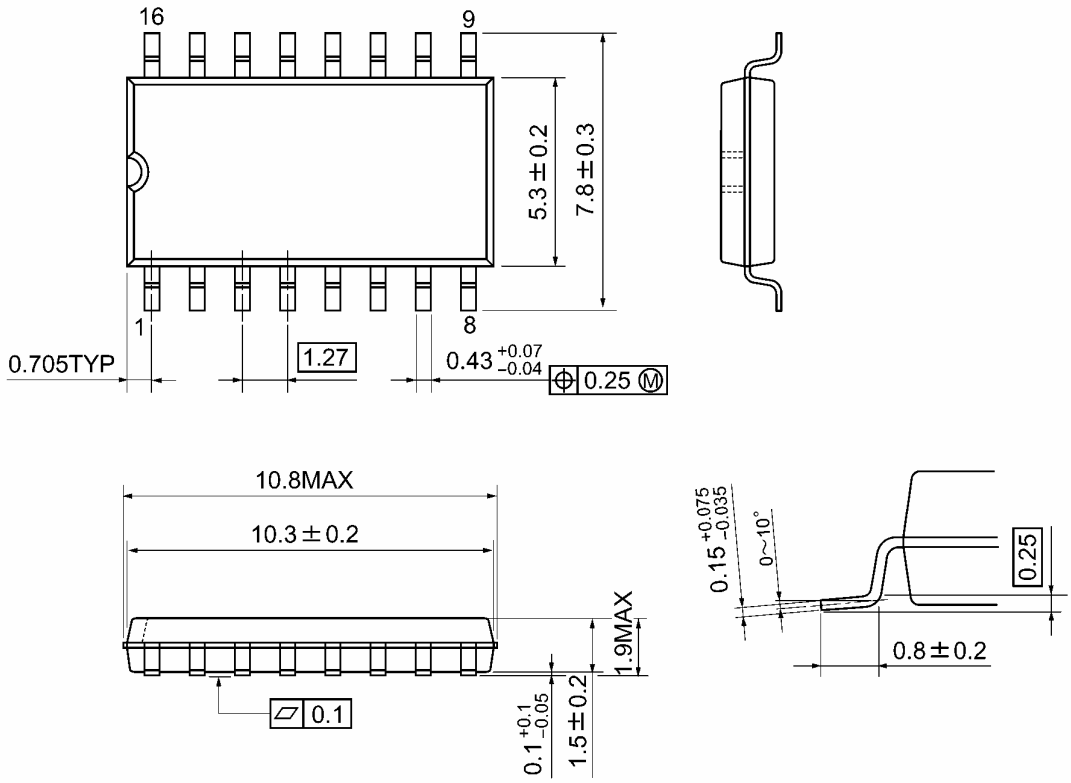
DIP16-P-300-2.54A Unit : mm



Weight: 1.00 g (typ.)

Package Dimensions

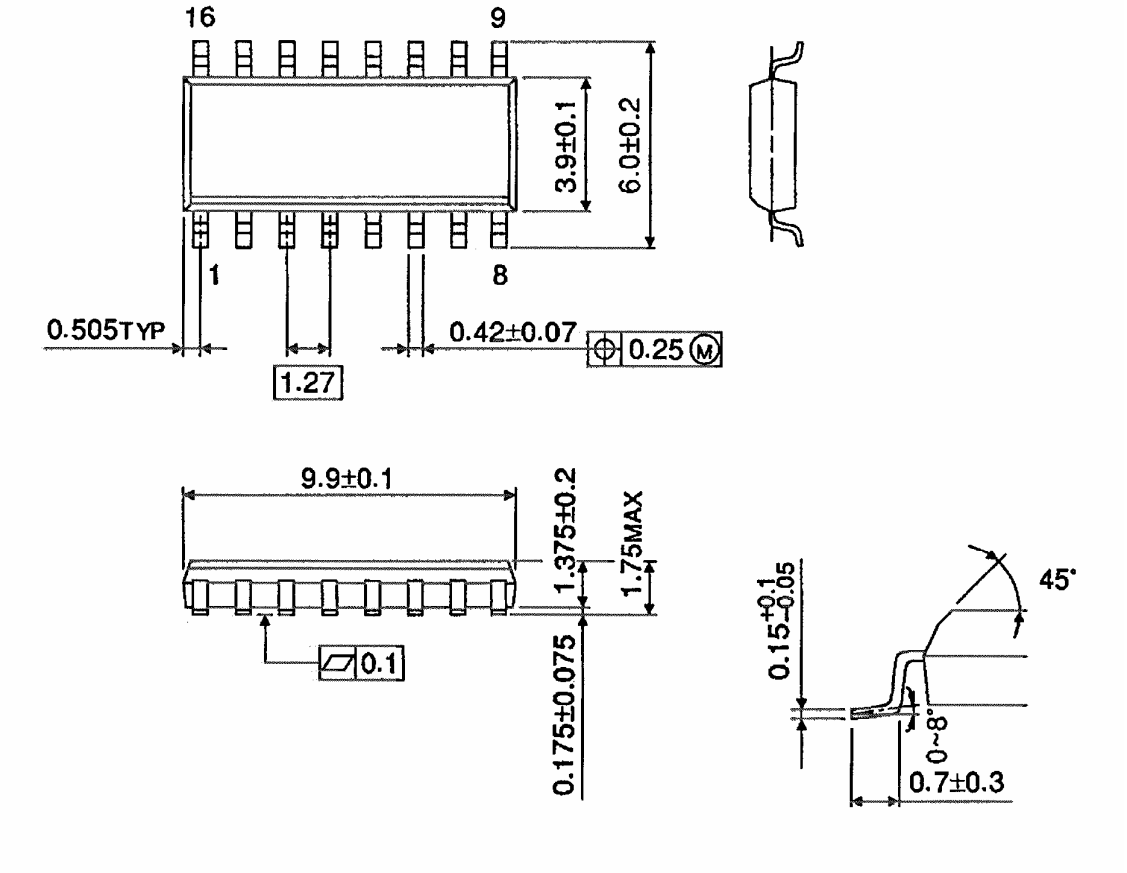
SOP16-P-300-1.27A Unit: mm



Weight: 0.18 g (typ.)

Package Dimensions (Note)

SOL16-P-150-1.27 Unit : mm



Note: This package is not available in Japan.

Weight: 0.13 g (typ.)

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20070701-EN GENERAL

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